

PUMH1

NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

14 November 2022

Product data sheet

1. General description

NPN/NPN Resistor-Equipped double Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- · Control of IC inputs
- · Replaces general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See section "Test information" for resistor calculation and test conditions.



NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	D. D. D.	
3	O2	output (collector) TR2	<u> </u>	R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2	0	TR1 R2 R1
6	01	output (collector) TR1	☐1 ☐2 ☐3 TSSOP6 (SOT363)	GND1 I1 O2
				aaa-019894

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMH1		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMH1	H%2

[1] % = placeholder for manufacturing site code

NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

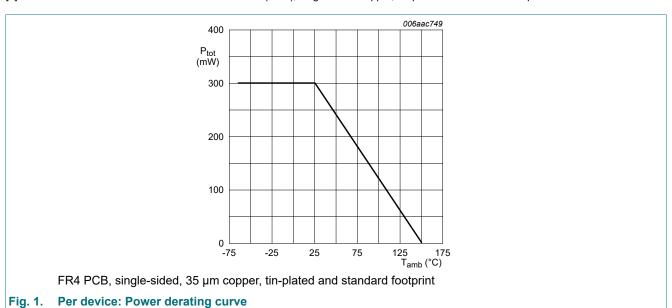
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or			'		
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
VI	input voltage	positive		-	40	V
		negative		-	-10	V
Io	output current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device				'		'
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

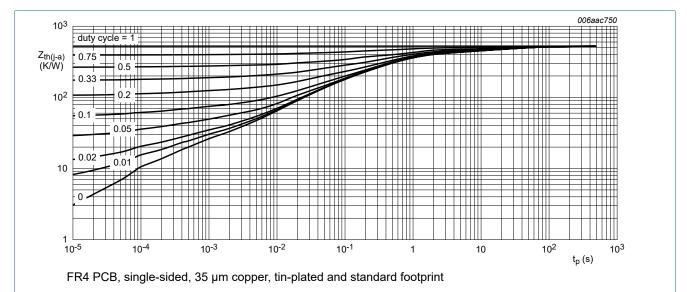


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

10. Characteristics

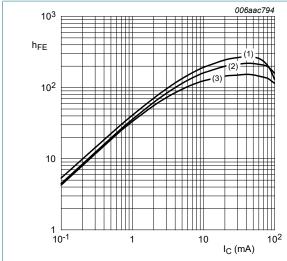
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0 A; T_{amb} = 25 °C$		50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	T _{amb} = 25 °C		50	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	I _C = 0 A; I _E = 100 A; T _{amb} = 25 °C		10	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO} collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	100	nA	
	current	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	180	μΑ
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 5 mA; T _{amb} = 25 °C		60	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	150	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	1.1	0.8	V
V _{I(on)}	on-state input voltage	$V_{CE} = 0.3 \text{ V; } I_{C} = 5 \text{ mA; } T_{amb} = 25 \text{ °C}$		2.5	1.7	-	V
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	2.5	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	230	-	MHz

^[1] See section "Test information" for resistor calculation and test conditions.

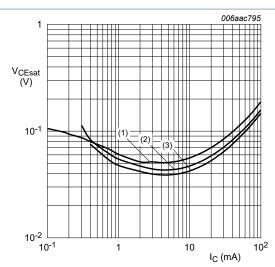
^[2] Characteristics of built-in transistor

NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω



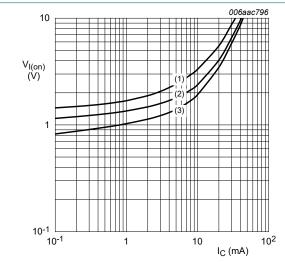
V_{CE} = 5 V (1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) T_{amb} = -40 °C

Fig. 3. DC current gain as a function of collector current; typical values



 $I_{C}/I_{B} = 20$ (1) $T_{amb} = 100 \, ^{\circ}C$ (2) $T_{amb} = 25 \, ^{\circ}C$ (3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

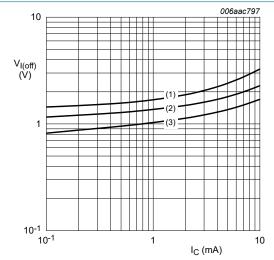


 V_{CE} = 0.3 V

(1) $T_{amb} = -40 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$

(3) $T_{amb} = 100 \, ^{\circ}C$





 $V_{CE} = 5 V$

(1) $T_{amb} = -40 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = 100 \, ^{\circ}C$

Off-state input voltage as a function of collector current; typical values

NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

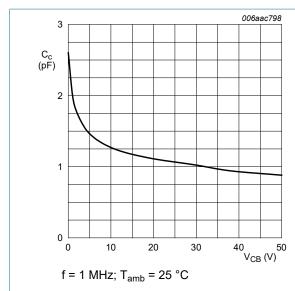


Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values

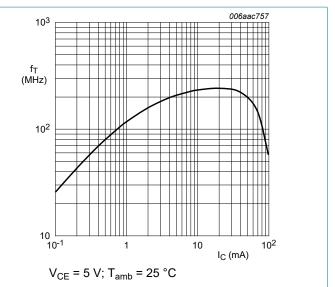


Fig. 8. Transition frequency as a function of collector current; typical values of built-in transistor

NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

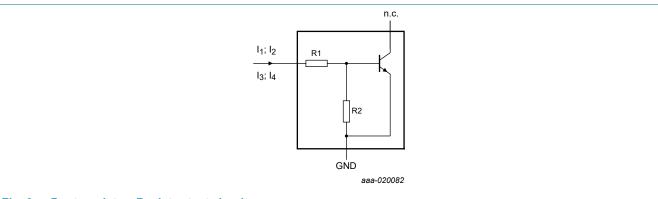


Fig. 9. Per transistor: Resistor test circuit

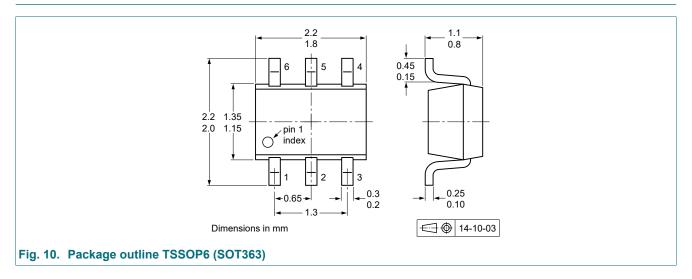
Resistor test conditions

Table 8. Resistor test conditions

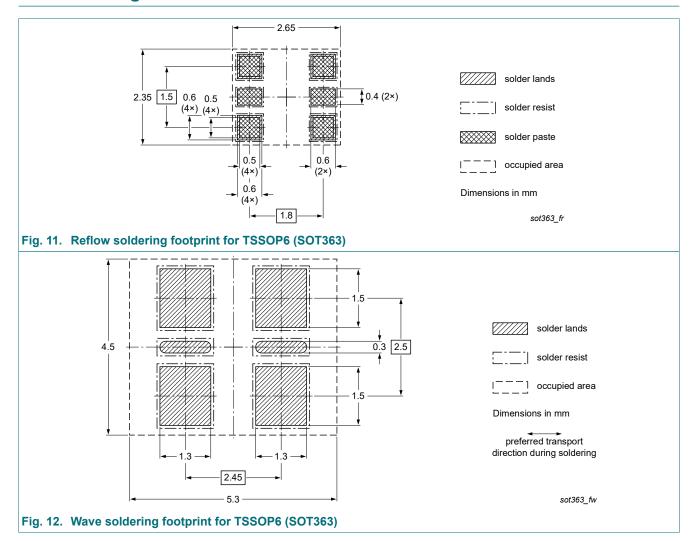
Type number	R1 (kΩ)	R2 (kΩ)	Test conditions	Test conditions				
			I ₁	l ₂	l ₃	14		
PUMH1-Q	22	22	150 µA	230 μΑ	-150 µA	-230 µA		

NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

12. Package outline



13. Soldering



NPN/NPN resistor-equipped double transistor; R1 = 22 k Ω , R2 = 22 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMH1 v.6	20221114	Product data sheet	-	PEMH1_PUMH1 v.5
Modifications:	Nexperia Legal texts have bee Data sheet with two Characteristics: Para	en adapted to the new contypes is separated into two ameters for breakdown volume at 25 °C corrected moved	mpany name where appi vo single data sheets oltages added	
PEMH1_PUMH1 v.5	20111202	Product data sheet	-	PEMH1_PUMH1 v.4
PEMH1_PUMH1 v.4	20031008	Product data sheet	-	PEMH1 v.1 PUMH1 v.3
PEMH1 v.1	20011022	Preliminary data sheet	-	-
PUMH1 v.3	19990520	Product specification	-	-
PUMH1 v.2	19980806	Product specification	-	PUMH1 v.1
PUMH1 v.1	19971212	Product specification	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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PUMH⁻

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Contents

1.	General description	1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	. 3
9.	Thermal characteristics	. 4
10.	Characteristics	5
11.	Test information	8
12.	Package outline	. 9
13.	Soldering	. 9
14.	Revision history	10
	Legal information	

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12 / 12

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